## CT430 POWER MEASUREMENT MODULE

By Allegro MicroSystems

## INTRODUCTION

This application note is for a power measurement module based on Crocus Technology's CT43x contact current sensor. It discusses PCB design guidelines and how to interface with an external MCU for reading all components of a power measurement, e.g. RMS values, active and passive power, etc.
The CT43x devices are a family of high-bandwidth and lownoise current sensors that offer accurate measurements for a wide variety of enterprise and industrial applications.

## HIGH-LEVEL DESIGN

The power meter is a module that conditions and reads current and voltage analog values, quantizes them using analog-todigital converters (ADCs), and based on the voltage and current values, calculates instantaneous and RMS values. It provides an SPI interface for the end user to readout the power values from the module using its own microcontroller unit. Figure 1 shows the high-level diagram of this module.


Figure 1: Power module block diagram

## MODULE PCB OVERVIEW

## Inputs and Outputs

The module's I/O consist of a high current conducting path through the IP+ and IP- pins (shown in Figure 1), voltage monitoring inputs, CT43x signals, and SPI communication pins, as illustrated in Figure 2.


## Placing the module in line with the load

As shown in Figure 3, the current conducting path passes from IP+ through the CT43x and out IP- to reach the load. This is considered 'high-side' current sensing. In the high-side configuration, the voltage monitoring input $(\mathrm{V}+)$ can be connected directly to the $\mathrm{IP}+$ on PCB .


Figure 3: Module circuit connection
Since the module already has a trace between IP+ and V+ then only the negative voltage monitor pin (V-) needs to be connected to the negative or neutral side of the voltage supply. If the module is not placed on the load's high side, then both voltage inputs are required to be connected to the module's $V+$ and $V$ - pins. In this case, the $P C B$ trace from IP+ to $V+$ must be cut, as shown in Figure 4.


Figure 4: Cutting the path between IP+ and V+

## Voltage Sensing

For high voltage measurement, the input voltage needs to be stepped down and isolated before reaching the microcontroller. A step-down IC or a simple resistive circuit can be used for that purpose.
Figure 5 shows the step-down resistive circuit consisting of four $1 \mathrm{M} \Omega$ resistors ( $\mathrm{R}_{\text {ISO }}$ ) to isolate the $\mathrm{V}+$ and V - high-voltage parts from the digital low-voltage side. If an external step-down circuit is used this resistive network needs to be bypassed and disabled by connecting J3 and J4.


Figure 5: J3 and J4 jumpers to bypass the isolation

## Choosing $R_{\text {SNSE }}$ for Voltage Measurement

The $R_{I S O}$ isolation network is connected across the $R_{\text {SNSE }}$ resistor. The voltage difference on both sides of $R_{\text {SNSE }}$ will be measured by the MCU to quantize the supply voltage. The value of $R_{\text {SNSE }}$ depends on the maximum voltage between $\mathrm{V}+$ and V - and must be chosen so that 625 mV (max) is measured across $R_{\text {SNSE }}$ for (V+ - V-). In this case, for correct measurements the input voltage cannot exceed 0.625 V . The ICs will be damaged if greater than 5.5 V is applied.

The equation for choosing the appropriate value for $\mathrm{R}_{\text {SNSE }}$ is:

$$
R_{S N S E}=R_{I S O} \times \frac{0.625}{\left(V_{\text {high-max }}-0.625\right)}
$$

For example, to measure 300 V on the high side, and with $\mathrm{R}_{\text {ISO }}$ of $4 \mathrm{M}(4 \times 1 \mathrm{M} \Omega)$, a value of $R_{\text {SNSE }} \sim 8.2 \mathrm{~K} \Omega$ is required.

## ATTINY426 PROGRAMMING

## Microcontroller

Figure 6 shows the module's ATtiny 426 MCU and the required pin connections. This includes CT43x OUT and VREF pins, stepped down VL+ and VL- voltage inputs, SPI interface pins (MOSI, MISO, SCK and SS), supply and UPDI programming pin.


Figure 6: ATtiny426 Connections

## Programming the ATtiny

The ATtiny's C++ firmware was developed using the Microchip

Studio IDE environment. The same IDE will both compile and program the MCU.

Microchip's ATMEL-ICE debugger/programmer supports the UPDI pin for programming the ATtiny MCU. To avoid accidental damage, the programmer must be disconnected while working with high voltages.
The debugger requires only three connections to the ATtiny: UPDI, VDD and GND. The debugger does not power-up the ATtiny, the VDD and GND connections provide power feedback to the debugger. Figure 7 shows the three pins required for programming.


Figure 7: Pins required for programming

## Operating Voltage

The PCB module's CT43x can operate with either a 3.3V or 5.0 $V$ supply. Fortunately, the ATtiny can operate with either voltage.

## CALCULATING POWER VALUES

The ATtiny 426 samples the current and voltage signals every $250 \mu \mathrm{~s}$ (Figure 8) and stores the quantized values in registers (Table 1) as instantaneous values. The module monitors the voltage value to detect the zero-crossing moment. Upon its detection, RMS values and power components are calculated.


Figure 8: AC Cycle Current and Voltage Sampling
Below are brief descriptions of the calculated values.
Quantized instantaneous values: $I_{\text {inst }} \& V_{\text {inst }}$ :
The instantaneous values are the last quantized current and voltage values from the ADCs.

## Calculated RMS values $I_{R M S} \& V_{R M S}$ :

The RMS values are based on discrete current and voltage measurements taken every $250 \mu$ s during a sinusoidal AC cycle.

Their values are calculated using the following equations:

$$
I_{R M S}=\sqrt{\frac{\sum_{n=0}^{n=N-1} I_{n}^{2}}{N}} \quad V_{R M S}=\sqrt{\frac{\sum_{n=0}^{n=N-1} V_{n}^{2}}{N}}
$$

In which, $I_{n}$ and $V_{n}$ are instantaneous values and $N$ is the number of samples during the sinusoidal AC cycle.

## Calculated Apparent Power $\mathrm{P}_{\text {apparent }}$ :

$P_{\text {apparent }}$ is calculated using the RMS values:

$$
\mathrm{P}_{\text {apparent }}=\mathrm{I}_{R M S} \times \mathrm{V}_{R M S}
$$

## Calculated Active/Reactive Power

$P_{\text {active }} \& P_{\text {reactive }}$ :
Calculated active power is based on the instantaneous values:

$$
P_{\text {active }}=\frac{\sum_{n=0}^{n=N-1} I_{n} \times V_{n}}{N}
$$

Consequently, reactive or imaginary power is calculated by:

$$
P_{\text {reactive }}=\sqrt{P_{\text {apparent }}^{2}-P_{\text {active }}^{2}}
$$

## Calculated Power Factor PF:

Power Factor is the ratio between active and apparent power:

$$
\text { PowerFactor }=\frac{P_{\text {active }}}{P_{\text {apparent }}}
$$

## Sign of Power Factor and Reactive Power:

Sign of PF and $P_{\text {reactive }}$ determines whether the current sign signal is lagging or leading, the load is capacitive of inductive and whether the power is produced or consumed by the load (Figure 9).


Figure 9: Power Factor and Apparent Power

Table 1: ATtiny Register Address Space

| Address | Bit Positions |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 31 | 30 | 29 | 28 | 27 | 26 | 25 | 24 | 23 | 22 | 21 | 20 | 19 | 18 | 17 | 16 | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| 0x20 |  |  |  |  |  | $I_{\mathrm{rms}}$ |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  | $\mathrm{V}_{\text {rms }}$ |  |  |  |  |  |  |  |  |  |  |
| $0 \times 21$ | $\mathrm{P}_{\text {reactive }}$ |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  | $\mathrm{P}_{\text {active }}$ |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| 0x22 |  |  |  | $\begin{aligned} & \frac{4}{0} \\ & 3_{0}^{0} \\ & \frac{0}{0} \\ & .0 \\ & \hline 0 \end{aligned}$ | - | (Pf) Power Factor |  |  |  |  |  |  |  |  |  |  | $\mathrm{P}_{\text {apparent }}$ |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| 0x25 |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  | numpts |  |  |  |  |  |  |  |  |
| $0 \times 2 \mathrm{~A}$ |  |  |  |  | $\mathrm{I}_{\text {inst }}$ |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  | $V_{\text {inst }}$ |  |  |  |  |  |  |  |  |  |  |  |
| 0x2C |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  | $\mathrm{P}_{\text {inst }}$ |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |



Figure 10: SPI Communication Protocol

## REGISTER DEFINITION

## SPI interface

The module provides an SPI interface for register value readouts. Every readout is a 32-byte word shifted out after receiving an 8 -bit register address (Figure 11). The current data is in response to the previous given address. The response of the current address will be shifted out on the next SPI readout.
The address part can take the values described in Table 1.
$0 \times 20: I_{\text {RMS }}-V_{R M S}$
$I_{\text {RMS }}$ and $V_{\text {RMS }}$ are 11-bit unsigned integer values. The range and conversion information is provided in Table 2.

Table 2: $0 \times 20: I_{R M S}$ and $V_{R M S}$

|  | Range | Conversion Formula | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{RMS}}$ | $0-2047$ | $\mathrm{I}_{\mathrm{RMS}} \times 0.03$ | A |
| $\mathrm{~V}_{\mathrm{RMS}}$ | $0-2047$ | $\mathrm{~V}_{\mathrm{RMS}} \times 0.3 \times \frac{R_{I S O} \times R_{S N S E}}{R_{S N S E}}$ | mV |

$0 \times 21: P_{\text {reactive }}-P_{\text {active }}$
The active and reactive powers are two 16-bit signed integer values. Table 3 shows the relationship between their value and the real physical values.

Table 3: $0 \times 21: P_{\text {reactive }}-P_{\text {active }}$

|  | Range | Conversion Formula | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{RMS}}$ | -32768 to 32767 | $\mathrm{P}_{\text {active }} \times 2.3 \times \frac{R_{I S O} \times R_{S N S E}}{R_{S N S E}}$ | mVAR |
| $\mathrm{V}_{\mathrm{RMS}}$ | -32768 to 32767 | $\mathrm{P}_{\mathrm{active}} \times 2.3 \times \frac{R_{I S O} \times R_{S N S E}}{R_{S N S E}}$ | mW |

0x22: Apparent Power - Power Factor and Signs
Apparent power is a 12 -bit unsigned integer value. Table 4 shows the relation between their value and the real physical value.

Power Factor is an 11-bit signed fractional value between. Table 4 shows how to convert the digital value to the fractional value.
Negative or positive sign for reactive power and power factor determines the type of load and phase relation between current and voltage signals (Figure 10).

Table 4: $0 \times 22: P_{\text {apparent }}-$ PF, Sign $_{\text {react }} \&$ Sign $_{p f}$

|  | Range | Conversion Formula | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{P}_{\text {apparent }}$ | -32768 to <br> 32767 | $\mathrm{P}_{\text {reactive }} \times 2.3 \times$ <br> $\frac{R_{I S} \times R_{S N S E}}{R_{S N S E}}$ | mVA |
| PF | -32768 to <br> 32767 | PowerFactor /1024 | - |
| SIGN $_{\text {pf }}$ | 0 to 1 | 1: Negative, 0: Positive | - |
| SIGN $_{\text {react }}$ | 0 to 1 | 1: Negative, 0: Positive | - |

$0 \times 25$ : Number of points numpts
Numpts is a 10-bit output that determines the value of N , as described in the previous section. $N$ is the number of current and voltage samples used to perform discrete integration of the RMS and power values. Numpts varies based on the frequency of the signal and is determined by the times of voltage signal zero-crossing.
$0 \times 20$ : Instantaneous current and voltage $I_{\text {inst }}-V_{\text {inst }}$
$I_{\text {inst }}$ and $V_{\text {inst }}$ are 12-bit signed integer values. Table 5 lists the range and conversion formula.

Table 5: $0 \times 20: I_{\text {inst }}$ and $V_{\text {inst }}$

|  | Range | Conversion Formula | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {inst }}$ | -2048 to 2047 | $\mathrm{I}_{\text {inst }} \times 0.3$ | A |
| $\mathrm{~V}_{\text {inst }}$ | -2048 to 2047 | $\mathrm{~V}_{\text {inst }} \times 0.3 \times \frac{R_{I S O} \times R_{S N S E}}{R_{S N S E}}$ | mV |

$0 \times 2 C: P_{\text {inst }}$
Instantaneous power is a 16-bit signed integer value. Table 6 shows the relationship between the value and the real physical value.

Table 6: $0 \times 2 C$ : $P_{\text {inst }}$

|  | Range | Conversion Formula | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{P}_{\text {inst }}$ | -32768 to 32767 | $\mathrm{P}_{\text {inst }} \times 2.3 \times \frac{R_{I S O} \times R_{S N S E}}{R_{S N S E}}$ | mW |

## PCB DESIGN

Two main considerations when designing the PCB layout are thermal dissipation and electrical isolation.
For optimum thermal dissipation, it is recommended to use a PCB copper layer thickness of 4.0 oz and above on both sides and internal layers, if any. Wide current carrying tracks, reinforced with thermal vias are recommended to minimize thermal resistance. Thermal vias create a low thermal resistance path between the PCB copper layers (Figures 11 and 13).
The integrated current carrying lead frame in the CT43x causes
self-heating which can affect overall performance if not managed. Device failure can occur if its junction temperature ( $T_{j}$ ) exceeds $155^{\circ} \mathrm{C}$. This PCB is designed to have a minimal thermal resistance for dissipating the heat generated within the CT43x current sensor.

An isolated module voltage is required on the digital logic side. The high-voltage GND must be completely isolated from the low-voltage GND. Any potential between these two grounds (caused by low-end power supplies) may result in wrong measurements.

Depending on the maximum sensed voltage, a creepage of a few to 10 mm may be needed between the high-side (current conducting circuitry) and the low side (digital outputs).


Figure 11: Power meter PCB Thermal Vias

## BILL OF MATERIALS (BOM)

The module uses surface mount components to maintain a small profile. This is shown in the PCB module BOM, Table 7.

The recommended decoupling and filtering capacitors are explained in the CT43x datasheet. Only two (2) CT43x differential outputs, OUT and VREF pins, are connected to the ATtiny microcontroller. The step-down resistive circuit consists of four (4) $1.0 \mathrm{M} \Omega$ resistors for providing an isolated voltage measurement across the R RNSE resistor. See Figure 12, the Power Meter Module schematic diagram.

## CONCLUSION

The power meter module is a usage example for the Crocus Technology CT430 TMR current sensor. When the module is placed in line with a load circuit, the on-board ATtiny 426 reads both load current and voltage to calculate and store multiple power values. These values are accessible to an external micro via the SPI bus to enable additional calculations and reporting capabilities.

Table 7: PCB Module BOM

| Part | Value | Device | Package | Description |
| :---: | :---: | :---: | :---: | :---: |
| 1M | $1.0 \mathrm{M} \Omega$ | R-EU_R0603 | R0603 | RESISTOR |
| 1M_1 | $1.0 \mathrm{M} \Omega$ | R-EU_R0603 | R0603 | RESISTOR |
| 1M_3 | $1.0 \mathrm{M} \Omega$ | R-EU_R0603 | R0603 | RESISTOR |
| 1M_4 | $1.0 \mathrm{M} \Omega$ | R-EU_R0603 | R0603 | RESISTOR |
| C1 | 100 pF | C-EUC0603 | C0603 | CAPACITOR |
| C2 |  | C-EUC0603 | C0603 | CAPACITOR |
| C3 | $1.0 \mu \mathrm{~F}$ | C-EUC0603 | C0603 | CAPACITOR |
| C4 | 1.0 nF | C-EUC0603 | C0603 | CAPACITOR |
| C5 | $1.0 \mu \mathrm{~F}$ | C-EUC0603 | C0603 | CAPACITOR |
| CT43x |  | $\begin{gathered} \text { CT430_CT430_SOI6_ } \\ \text { WIDE } \end{gathered}$ | CT430_SO16DW | CT430 Integrated Current Sensor |
| IC2 | ATTINY426-MU | ATTINY426-MU | $\begin{aligned} & \text { QFN40P300X300X90- } \\ & 21 \mathrm{~N} \end{aligned}$ | 8-bit Microcontrollers - MCU 20 MHz |
| J1 | 7461057 | 7461057 | 7461057 | PCB power element bush terminal |
| J2 | 7461057 | 7461057 | 7461057 | PCB power element bush terminal |
| J3 | J5MM | J5MM | 5 | Bridge |
| J4 | J5MM | J5MM | 5 | Bridge |
| JP1 |  | PINHD-1X2 | 1X02 | PIN HEADER |
| JP2 |  | PINHD-1X2 | 1X02 | PIN HEADER |
| R2 | $10 \mathrm{k} \Omega$ | R-EU_R0603 | R0603 | RESISTOR |
| R3 | $100 \mathrm{k} \Omega$ | R-EU_R0603 | R0603 | RESISTOR |
| R_SNSE | $8.2 \mathrm{k} \Omega$ | R-EU_R0603 | R0603 | RESISTOR |
| SV1 |  | MA04-1 | MA04-1 | PIN HEADER |
| UPDI | $\begin{aligned} & \text { TESTPOINT_TPS- } \\ & \text { PAD-036 } \end{aligned}$ | $\begin{aligned} & \text { TESTPOINT_TPS- } \\ & \text { PAD-036 } \end{aligned}$ | TESTPOINT_PAD-036 | TEST POINT PAD |
| V+ | $\begin{aligned} & \text { TESTPOINT_TPS- } \\ & \text { PAD-036 } \end{aligned}$ | $\begin{aligned} & \text { TESTPOINT_TPS- } \\ & \text { PAD-036 } \end{aligned}$ | TESTPOINT_PAD-036 | TEST POINT PAD |
| V- | $\begin{aligned} & \hline \text { TESTPOINT_TPS- } \\ & \text { PAD-036 } \end{aligned}$ | $\begin{aligned} & \text { TESTPOINT_TPS- } \\ & \text { PAD- } 03 \overline{6} \end{aligned}$ | TESTPOINT_PAD-036 | TEST POINT PAD |
| VINN1 | JUMPER-SMT_2_NC_ TRACE_SILK | JUMPER-SMT_2_NC_ TRACE_SILK | SMT-JUMPER_2_NC_ TRACE_SILK | Normally closed trace jumper |
| VINN2 | JUMPER-SMT_2_NC_ TRACE_SILK | JUMPER-SMT_2_NC_ TRACE_SILK | SMT-JUMPER_2_NC_ TRACE_SILK | Normally closed trace jumper |

## SCHEMATIC AND LAYOUT



Figure 12: Power Meter Module schematic

## PCB LAYOUT AND VIAS



Figure 13: Top and bottom PCB layout


Figure 14: Top and bottom Via placement

Revision History

| Number | Date | Description | Responsibility |
| :---: | :---: | :--- | :---: |
| 1 | December 11,2023 | Document rebrand and minor editorial updates | Tyler Hendrigan |

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